

GEMOLOGICAL INSTITUTE

# **ELECTRONIC COPY**

## LABORATORY GROWN DIAMOND REPORT

## PROPORTIONS

**CLARITY CHARACTERISTICS** 

**KEY TO SYMBOLS** 

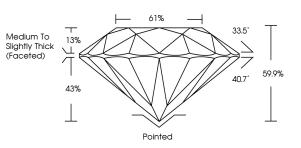
Red symbols indicate internal characteristics.

Green symbols indicate external characteristics.

July 17, 2024	
IGI Report Number	LG644471834
Description	LABORATORY GROWN DIAMOND
Shape and Cutting Style	ROUND BRILLIANT
Measurements	10.21 - 10.27 X 6.14 MM
GRADING RESULTS	
Carat Weight	4.00 CARATS
Color Grade	빈더님인더语
Clarity Grade	VS 1
Cut Grade	EXCELLENT
ADDITIONAL GRADING I	NFORMATION
Polish	EXCELLENT

Polish	EXCELLENT
Symmetry	EXCELLENT
Fluorescence	NONE
Inscription(s)	低利 LG644471834

Comments: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process. Type IIa



LG644471834

Report verification at igi.org



Sample Image Used

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July 17, 2024	
IGI Report Number	LG644471834
Description LA	BORATORY GROWN DIAMOND
Shape and Cutting Style	ROUND BRILLIANT
Measurements	10.21 - 10.27 X 6.14 MM
GRADING RESULTS	
Carat Weight	4.00 CARATS
Color Grade	F
Clarity Grade	VS 1
Cut Grade	EXCELLENT

LABORATORY GROWN DIAMOND REPORT

61% -33.5° 1.39 Medium To Slightly 59.9% Thick 40.7 43% (Faceted) Pointed

### ADDITIONAL GRADING INFORMATION

Polish	EXCELLENT
Symmetry	EXCELLENT
Fluorescence	NONE
Inscription(s)	(G) LG644471834
Comments: This Laboratory of created by Chemical Vapo process. Type IIa	



DEF	GHIJ	Faint	Very Light	Light
CLARITY	WS <sup>1-2</sup>	V\$ <sup>1-2</sup>	SI <sup>1-2</sup>	<sup>1-3</sup>
Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included





4 MM	4.00 CARATS	TO LO LO LO	I SA	EXCELLENT	86.9%	61%	Medium To Slightly Thick (Faceted)	Pointed	EXCELLENT	EXCELLENT	NONE	MBN LG644471834	Comments: This Laboratory Grown Dramond was reacted by Chemical Vapor Deposition (CVD) growth process. Nipe IIa
10.21 - 10.27 X 6.14 MM	Carat Weight	Color Grade	Clarity Grade	Cut Grade	Depth	Table	Girdle	Culet	Polish	Symmetry	Fluorescence	Inscription(s)	Comments: This Laboratory Grown created by Chemical (CVD) growth process Type IIa